Supporting Information

Band Engineered Ternary Solid Solution CdS_xSe_{1-x} -Sensitized Mesoscopic TiO₂ Solar Cells

Md. Anower Hossain,^a James Robert Jennings,^a Nripan Mathews,^b and Qing Wang^a*

^aDepartment of Materials Science and Engineering, Faculty of Engineering, NUSNNI-NanoCore,

National University of Singapore, Singapore 117576,

^bSchool of Materials Science and Engineering, Nanyang Technological University, Singapore 639798





Figure S1. X-ray diffraction patterns of CdS and CdSe-sensitized TiO₂ electrodes made on glass microscope slides before and after heat treatment. The standard 2θ values for TiO₂ (Anatase), wurtzite CdS and CdSe crystals are also shown for comparison.





Figure S2. IPCE (a) and *j*-*V* characteristics (b) of solar cells made with $6CdS_xSe_{1-x}$ and 5CdS/5CdSesensitized TiO₂ photoanodes (5 µm thick TiO₂ electrodes without scattering layers) with platinised FTO counter electrodes for impedance study.

Table S1. Characteristics of $6CdS_xSe_{1-x}$ and 5CdS/5CdSe-sensitized TiO₂ solar cells under simulated AM1.5 100 mW cm⁻² illumination made with platinised FTO cathode and TiO₂ electrodes (5 μ m transparent Degussa P25 layers) without scattering layers.

Photoanode	Sensitizer	Voc (V)	j_{sc} (mA.cm ⁻²)	<i>ff</i> (%)	η (%)
TiO ₂ (5 μm)	6CdS _x Se _{1-x}	0.539	12.57	43.83	2.97
	5CdS/5CdSe	0.563	12.70	41.76	3.00